



Tfw

Docket No.: 8734.225.00
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:
Seok-Woo LEE

Customer No.: 30827

Application No.: 10/648,401

Confirmation No. 5327

Filed: August 27, 2003

Art Unit: 2812

For: METHOD OF FABRICATING TOP GATE
TYPE THIN FILM TRANSISTOR HAVING
LOW TEMPERATURE POLYSILICON

Examiner: Stanetta D. Isaac

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

AMENDMENT

Sir:

In response to the Non-Final Office Action dated June 20, 2005 Applicant hereby requests entry of the following amendments.

INTRODUCTORY COMMENTS

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks begin on page 9 of this paper.